

Memory System Architecture

Read-only memory

Read-only memories (ROMs) are memory devices that the CPU can read but cannot write.

Many ROMs are factory programmed and there is no way to alter their contents (the term programming here means writing values into a ROM). These devices are denser and cheaper to manufacture than other type of ROM.

Programmable ROMs (PROMs): This type of ROM can be programmed by using special high current device to destroy (burn) the fuse that were manufactured into the device. The result of burning a PROM is that certain bits are always 0 and the rest are always 1. These values cannot be altered once written.

Erasable PROMs (EPROMs): This type of ROM is alterable, although not during ordinary use. A technician can program an EPROM off line, later completely erase its contents by using ultraviolet light, and then reprogram it.

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Read/Write Memory

Read/Write memories refer to memory devices can be read from and write into with equal ease. Two main types of read/write memory devices are static random access memories (SRAMs) and dynamic random access memories (DRAMs).

SRAMs: In SRAMs, the individual memory contents, once written, do not need to be further addressed or manipulated to hold their values. These devices are composed of fin-flongs that use a small current to maintain their contents. SRAMs are used mostly in CPU registers and other high speed storage devices. Some computers use them for **cache** and main memory. SRAMs are currently the fastest and most expensive of semiconductor memory circuit.

DRAMs: These are semiconductor memory devices in which the stored data will not remain permanently stored, even with power applied, unless the data are periodically rewritten into the memory. The latter operation is called the *refresh* operation. Although much cheaper than SRAMs, DRAMs are also slower and used mostly for main memory



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General Memory Operation

Although each type of memory is different in its internal operation, there are certain basic operating principles that are the same for all memory systems. Every memory system requires several different types of input and output lines to perform the following function:

Select the address in memory that is being accessed for READ or WRITE operation

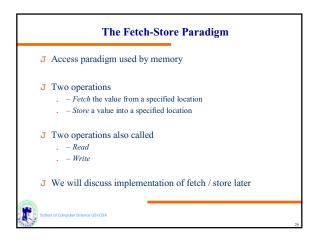
Select either READ or WRITE operation to be performed

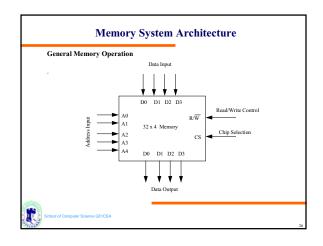
Supply the input data to be stored in memory during write operation

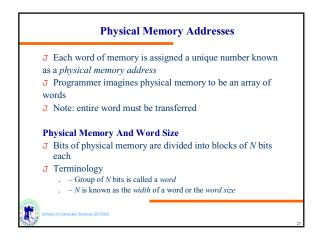
Hold the output data coming from memory during a read operation

Enable (or disable) the memory so that it will (or will not) respond to the address inputs and read/write command.

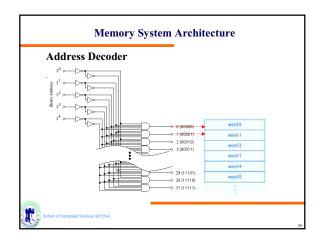
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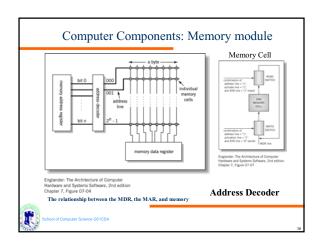


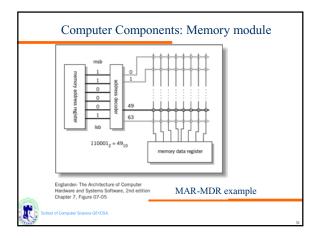


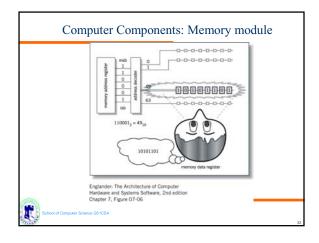


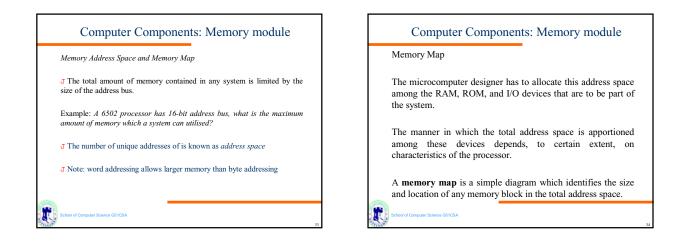
J Word siz	e = 32 bits	
physical address	32 bits	Physical memory is organized into
0	word 0	words, where a word
1	word 1	is equal to the
2	word 2	memory transfer size (number of bits can
3	word 3	be transferred
4	word 4	simultaneously).
5	word 5	Each read or write
	:	operation applies to an entire word.

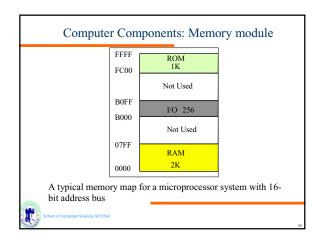


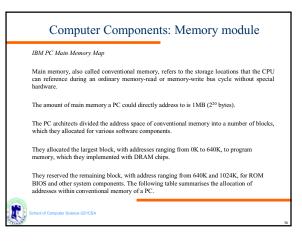












Address	PC Usage		
960K - 1024K	ROM BIOS		
880K - 960K	Unused	1536 - 640K	User RAM
848K - 880K	LIM data area	1152 - 1535	BASIC,
816K - 848K	LIM data area	0 - 1023	Special system RAM Interrupt-vector table
800K - 816K	Hard disk ROM		
784K - 800K	Unused		
768K - 784K	EGA ROM		
752K - 768K	Unused		
736K - 752K	CGA		
720K - 736K	Unused		
704K - 720K	MDA		
640K - 704K	EGA or VGA	_	

